



# Full Feature Peak Reducing EMI Solution

## Features

- Cypress PREMIS™ family offering
- Generates an EMI optimized clocking signal at the output
- Selectable output frequency range
- Single -1.25%, -3.75% down spread output
- Integrated loop filter components
- Operates with a 3.3 or 5V supply
- Low power CMOS design
- Available in 14-pin SOIC (Small Outline Integrated Circuit)

## Key Specifications

Supply Voltages: .....  $V_{DD} = 3.3V \pm 0.3V$   
or  $V_{DD} = 5V \pm 10\%$

Frequency Range: .....  $28 \text{ MHz} \leq F_{in} \leq 75 \text{ MHz}$

Crystal Reference Range: .....  $28 \text{ MHz} \leq F_{in} \leq 40 \text{ MHz}$

Cycle to Cycle Jitter: ..... 300 ps (max)

Selectable Spread Percentage: ..... -1.25% or -3.75%

Output Duty Cycle: ..... 40/60% (worst case)

Output Rise and Fall Time: ..... 5 ns (max)

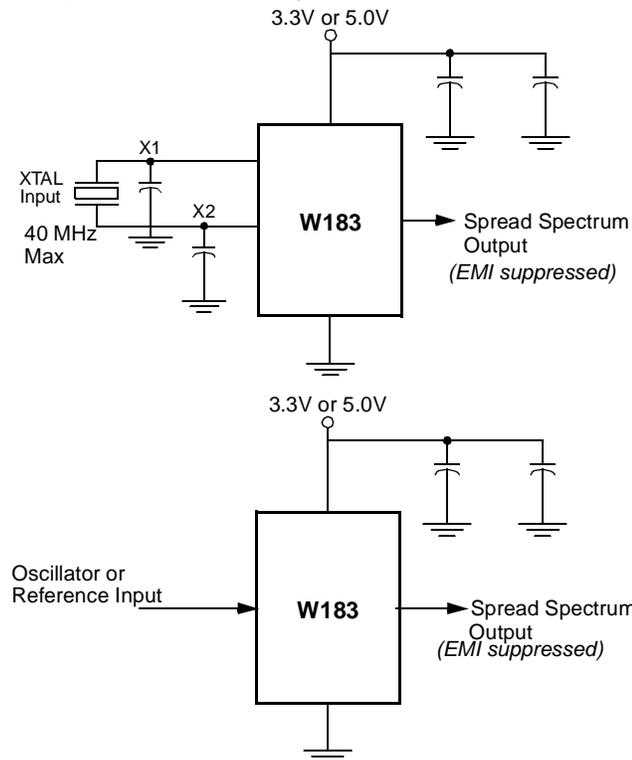
Table 1. Modulation Width Selection

| SS% | Output                                     |
|-----|--|
| 0   | $F_{in} \geq F_{out} \geq F_{in} - 1.25\%$ |
| 1   | $F_{in} \geq F_{out} \geq F_{in} - 3.75\%$ |

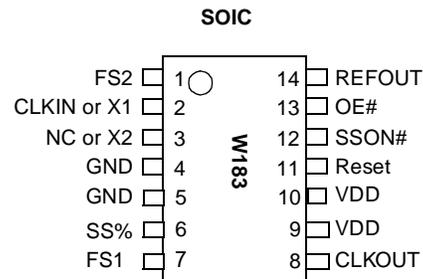
Table 2. Frequency Range Selection

| FS2 | FS1 | Frequency Range                                  |
|-----|-----|--|
| 0   | 0   | $28 \text{ MHz} \leq F_{IN} \leq 38 \text{ MHz}$ |
| 0   | 1   | $38 \text{ MHz} \leq F_{IN} \leq 48 \text{ MHz}$ |
| 1   | 0   | $46 \text{ MHz} \leq F_{IN} \leq 60 \text{ MHz}$ |
| 1   | 1   | $58 \text{ MHz} \leq F_{IN} \leq 75 \text{ MHz}$ |

## Simplified Block Diagram



## Pin Configuration



PREMIS is a trademark of Cypress Semiconductor Corporation.

**Pin Definitions**

| Pin Name    | Pin No. | Pin Type | Pin Description   |
|-------------|---------|----------|---|
| CLKOUT      | 8       | O        | <b>Output Modulated Frequency:</b> Frequency modulated copy of the input clock (SSON# asserted).  |
| REFOUT      | 14      | O        | <b>Non-Modulated Output:</b> This pin provides a copy of the reference frequency. This output will not have the Spread Spectrum feature regardless of the state of logic input SSON#.         |
| CLKIN or X1 | 2       | I        | <b>Crystal Connection or External Reference Frequency Input:</b> This pin has dual functions. It may either be connected to an external crystal, or to an external reference clock.           |
| NC or X2    | 3       | I        | <b>Crystal Connection:</b> Input connection for an external crystal. If using an external reference, this pin must be left unconnected.   |
| SSON#       | 12      | I        | <b>Spread Spectrum Control (Active LOW):</b> Asserting this signal (active LOW) turns the internal modulation waveform on. This pin has an internal pull-down resistor.                       |
| SS%         | 6       | I        | <b>Modulation Width Selection:</b> When Spread Spectrum feature is turned on, this pin is used to select the amount of variation and peak EMI reduction that is desired on the output signal. |
| OE#         | 13      | I        | <b>Output Enable (Active LOW):</b> When this pin is held HIGH, the output buffers are placed in a high-impedance mode.  |
| Reset       | 11      | I        | <b>Modulation Profile Restart:</b> A rising edge on this input restarts the modulation pattern at the beginning of its defined path.  |
| FS1:2       | 7, 1    | I        | <b>Frequency Selection Bits:</b> These pins select the frequency range of operation. Refer to <i>Table 2</i> . These pins have internal pull-up resistors.                                    |
| VDD         | 9,10    | P        | <b>Power Connection:</b> Connected to 3.3V or 5V power supply.  |
| GND         | 4,5     | G        | <b>Ground Connection:</b> Connect all ground pins to the common ground plane.   |

## Overview

The W183 product is one of a series of devices in the Cypress PREMIS family. The PREMIS family incorporates the latest advances in PLL spread spectrum frequency synthesizer techniques. By frequency modulating the output with a low frequency carrier, peak EMI is greatly reduced. Use of this technology allows systems to pass increasingly difficult EMI testing without resorting to costly shielding or redesign.

In a system, not only is EMI reduced in the various clock lines, but also in all signals which are synchronized to the clock. Therefore, the benefits of using this technology increase with the number of address and data lines in the system. The Simplified Block Diagram shows a simple implementation.

## Functional Description

The W183 uses a phase-locked loop (PLL) to frequency modulate an input clock. The result is an output clock whose frequency is slowly swept over a narrow band near the input signal. The basic circuit topology is shown in *Figure 1*. The input reference signal is divided by Q and fed to the phase detector. A signal from the VCO is divided by P and fed back to the phase detector also. The PLL will force the frequency of the VCO output signal to change until the divided output signal and the divided reference signal match at the phase detector input. The output frequency is then equal to the ratio of P/Q

times the reference frequency. (Note: For the W183 the output frequency is equal to the input frequency.) The unique feature of the Spread Spectrum Frequency Timing Generator is that a modulating waveform is superimposed at the input to the VCO. This causes the VCO output to be slowly swept across a pre-determined frequency band.

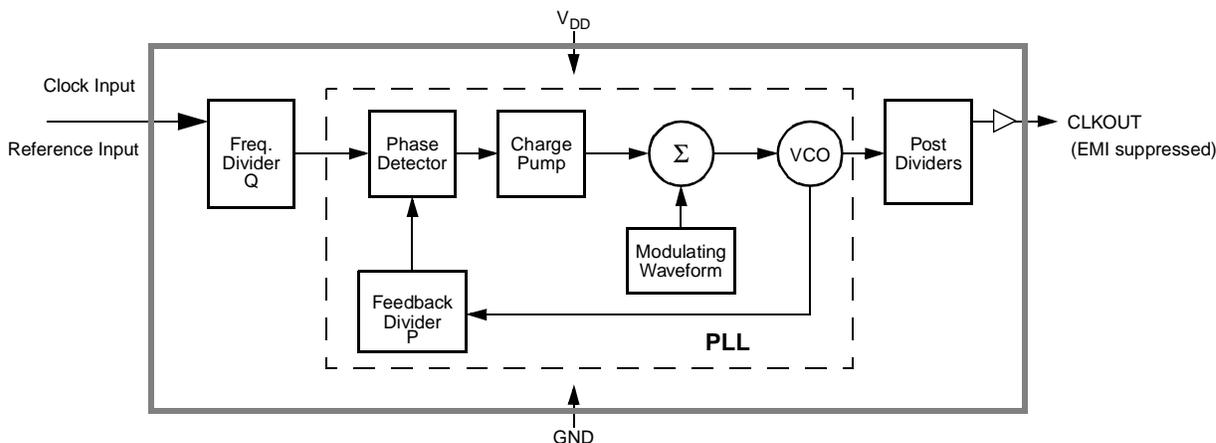
Because the modulating frequency is typically 1000 times slower than the fundamental clock, the spread spectrum process has little impact on system performance.

### Frequency Selection With SSFTG

In Spread Spectrum Frequency Timing Generation, EMI reduction depends on the shape, modulation percentage, and frequency of the modulating waveform. While the shape and frequency of the modulating waveform are fixed for a given frequency, the modulation percentage may be varied.

Using frequency select bits (FS2:1 pins), the frequency range can be set (see *Table 2*). Spreading percentage is set with pin SS% as shown in *Table 1*.

A larger spreading percentage improves EMI reduction. However, large spread percentages may either exceed system maximum frequency ratings or lower the average frequency to a point where performance is affected. For these reasons, spreading percentages between 0.5% and 2.5% are most common.



**Figure 1. Functional Block Diagram**

## Spread Spectrum Frequency Timing Generation

The benefits of using Spread Spectrum Frequency Timing Generation are depicted in *Figure 2*. An EMI emission profile of a clock harmonic is shown.

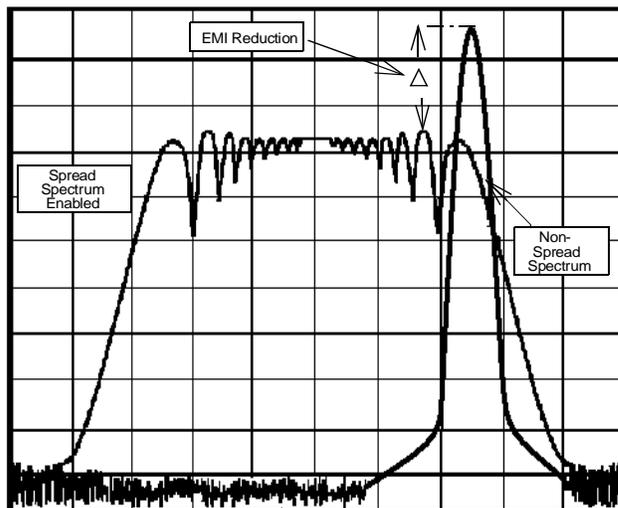
Contrast the typical clock EMI with the Cypress Spread Spectrum Frequency Timing Generation EMI. Notice the spike in the typical clock. This spike can make systems fail quasi-peak EMI testing. The FCC and other regulatory agencies test for peak emissions. With spread spectrum enabled, the peak energy is much lower (at least 8 dB) because the energy is spread out across a wider bandwidth.

### Modulating Waveform

The shape of the modulating waveform is critical to EMI reduction. The modulation scheme used to accomplish the maximum reduction in EMI is shown in *Figure 3*. The period of the modulation is shown as a percentage of the period length along the X axis. The amount that the frequency is varied is shown along the Y axis, also shown as a percentage of the total frequency spread.

Cypress frequency selection tables express the modulation percentage in two ways. The first method displays the spreading frequency band as a percent of the programmed average output frequency, symmetric about the programmed average frequency. This method is always shown using the expression  $f_{\text{Center}} \pm X_{\text{MOD}}\%$  in the frequency spread selection table.

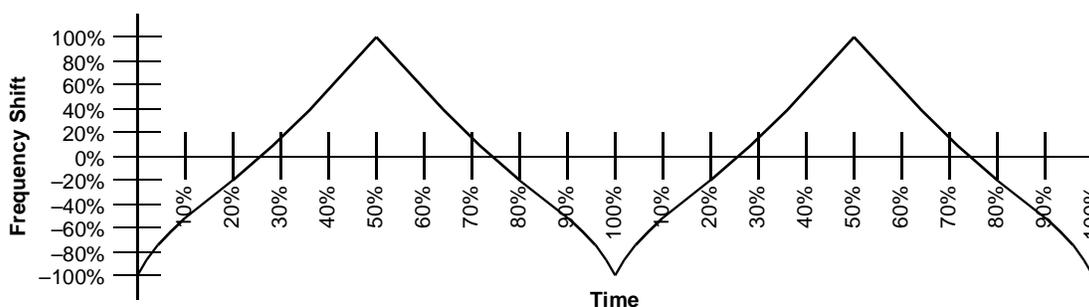
The second approach is to specify the maximum operating frequency and the spreading band as a percentage of this frequency. The output signal is swept from the lower edge of the band to the maximum frequency. The expression for this approach is  $f_{\text{MAX}} - X_{\text{MOD}}\%$ . Whenever this expression is used, Cypress has taken care to ensure that  $f_{\text{MAX}}$  will never be exceeded. This is important in applications where the clock drives components with tight maximum clock speed specifications.



**Figure 2. Typical Clock and SSFTG Comparison**

### SSON# Pin

An internal pull-down resistor defaults the chip into spread spectrum mode. When the SSON# pin is asserted (active LOW) the spreading feature is enabled. Spreading feature is disabled when SSON# is set HIGH ( $V_{\text{DD}}$ ).



**Figure 3. Modulation Waveform Profile**

### Absolute Maximum Ratings

Stresses greater than those listed in this table may cause permanent damage to the device. These represent a stress rating only. Operation of the device at these or any other conditions

above those specified in the operating sections of this specification is not implied. Maximum conditions for extended periods may affect reliability.

| Parameter        | Description                            | Rating       | Unit |
|------------------|--|--------------|------|
| $V_{DD}, V_{IN}$ | Voltage on any pin with respect to GND | -0.5 to +7.0 | V    |
| $T_{STG}$        | Storage Temperature                    | -65 to +150  | °C   |
| $T_A$            | Operating Temperature                  | 0 to +70     | °C   |
| $T_B$            | Ambient Temperature under Bias         | -55 to +125  | °C   |
| $P_D$            | Power Dissipation                      | 0.5          | W    |

### DC Electrical Characteristics: $0^{\circ}\text{C} < T_A < 70^{\circ}\text{C}$ , $V_{DD} = 3.3\text{V} \pm 0.3\text{V}$

| Parameter | Description            | Test Condition                            | Min | Typ | Max | Unit |
|-----------|------------------------|---|-----|-----|-----|------|
| $I_{DD}$  | Supply Current         |   |     | 18  | 32  | mA   |
| $t_{ON}$  | Power Up Time          | First locked clock cycle after Power Good |     |     | 5   | ms   |
| $V_{IL}$  | Input Low Voltage      |   |     |     | 0.8 | V    |
| $V_{IH}$  | Input High Voltage     |   | 2.4 |     |     | V    |
| $V_{OL}$  | Output Low Voltage     |   |     |     | 0.4 | V    |
| $V_{OH}$  | Output High Voltage    |   | 2.4 |     |     | V    |
| $I_{IL}$  | Input Low Current      | Note 1                                    | -50 |     |     | μA   |
| $I_{IH}$  | Input High Current     | Note 1                                    |     |     | 50  | μA   |
| $I_{OL}$  | Output Low Current     | @ 0.4V, $V_{DD} = 3.3\text{V}$            |     | 15  |     | mA   |
| $I_{OH}$  | Output High Current    | @ 2.4V, $V_{DD} = 3.3\text{V}$            |     | 15  |     | mA   |
| $C_I$     | Input Capacitance      |   |     |     | 7   | pF   |
| $R_P$     | Input Pull-Up Resistor |   |     | 500 |     | kΩ   |
| $Z_{OUT}$ | Clock Output Impedance |   |     | 25  |     | Ω    |

**Note:**

- Inputs FS1:2 have a pull-up resistor, Input SSON# has a pull-down resistor.

**DC Electrical Characteristics:**  $0^{\circ}\text{C} < T_A < 70^{\circ}\text{C}$ ,  $V_{DD} = 5\text{V} \pm 10\%$ 

| Parameter | Description            | Test Condition                            | Min         | Typ | Max          | Unit          |
|-----------|------------------------|---|-------------|-----|--------------|---------------|
| $I_{DD}$  | Supply Current         |   |             | 30  | 50           | mA            |
| $t_{ON}$  | Power Up Time          | First locked clock cycle after Power Good |             |     | 5            | ms            |
| $V_{IL}$  | Input Low Voltage      |   |             |     | $0.15V_{DD}$ | V             |
| $V_{IH}$  | Input High Voltage     |   | $0.7V_{DD}$ |     |              | V             |
| $V_{OL}$  | Output Low Voltage     |   |             |     | 0.4          | V             |
| $V_{OH}$  | Output High Voltage    |   | 2.4         |     |              | V             |
| $I_{IL}$  | Input Low Current      | Note 2                                    | -50         |     |              | $\mu\text{A}$ |
| $I_{IH}$  | Input High Current     | Note 2                                    |             |     | 50           | $\mu\text{A}$ |
| $I_{OL}$  | Output Low Current     | @ 0.4V, $V_{DD} = 5\text{V}$              |             | 24  |              | mA            |
| $I_{OH}$  | Output High Current    | @ 2.4V, $V_{DD} = 5\text{V}$              |             | 24  |              | mA            |
| $C_I$     | Input Capacitance      |   |             |     | 7            | pF            |
| $R_P$     | Input Pull-Up Resistor |   |             | 500 |              | k $\Omega$    |
| $Z_{OUT}$ | Clock Output Impedance |   |             | 25  |              | $\Omega$      |

**AC Electrical Characteristics:**  $T_A = 0^{\circ}\text{C}$  to  $+70^{\circ}\text{C}$ ,  $V_{DD} = 3.3\text{V} \pm 0.3\text{V}$  or  $5\text{V} \pm 10\%$ 

| Symbol     | Parameter                    | Test Condition   | Min | Typ | Max | Unit |
|------------|------------------------------|--|-----|-----|-----|------|
| $f_{IN}$   | Input Frequency              | Input Clock  | 28  |     | 75  | MHz  |
| $f_{OUT}$  | Output Frequency             | Spread Off   | 28  |     | 75  | MHz  |
| $f_{XOSC}$ | Crystal Oscillator Frequency |  | 28  |     | 40  | MHz  |
| $t_R$      | Output Rise Time             | 15-pF load, 0.8V–2.4V  |     | 2   | 5   | ns   |
| $t_F$      | Output Fall Time             | 15-pF load, 2.4V–0.8V  |     | 2   | 5   | ns   |
| $t_{OD}$   | Output Duty Cycle            | 15-pF load   | 40  |     | 60  | %    |
| $t_{ID}$   | Input Duty Cycle             |  | 40  |     | 60  | %    |
| $t_{JCYC}$ | Jitter, Cycle-to-Cycle       |  |     | 250 | 300 | ps   |
|            | Harmonic Reduction           | $f_{out} = 40\text{ MHz}$ , third harmonic measured, reference board, 15-pF load | 8   |     |     | dB   |

**Note:**

- Inputs FS2:1 have a pull-up resistor, Input SSON# has a pull-down resistor.

## Application Information

### Recommended Circuit Configuration

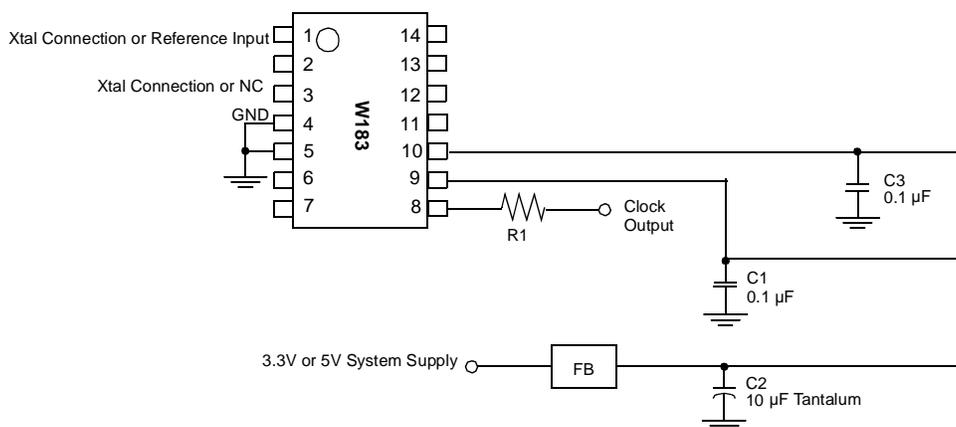
For optimum performance in system applications the power supply decoupling scheme shown in *Figure 4* should be used.

VDD decoupling is important to both reduce phase jitter and EMI radiation. The 0.1- $\mu\text{F}$  decoupling capacitor should be placed as close to the  $V_{DD}$  pin as possible, otherwise the in-

creased trace inductance will negate its decoupling capability. The 10- $\mu\text{F}$  decoupling capacitor shown should be a tantalum type. For further EMI protection, the  $V_{DD}$  connection can be made via a ferrite bead, as shown.

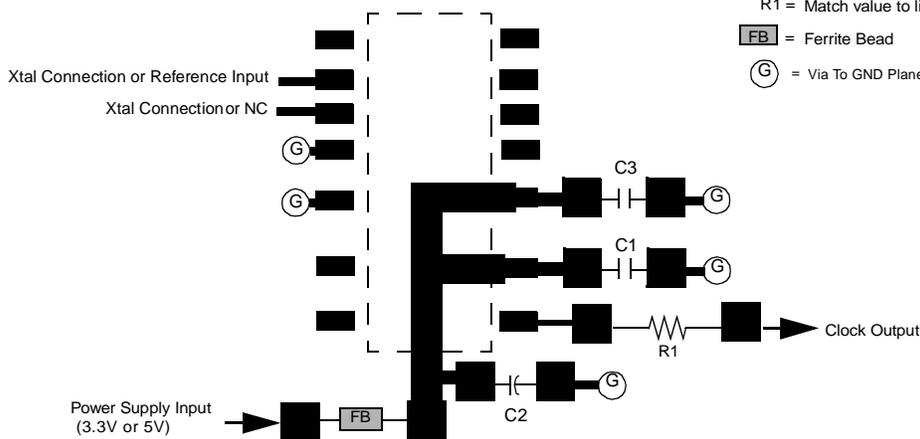
### Recommended Board Layout

*Figure 5* shows a recommended a 2-layer board layout



**Figure 4. Recommended Circuit Configuration**

- C1, C3 = High frequency supply decoupling capacitor (0.1- $\mu\text{F}$  recommended).
- C2 = Common supply low frequency decoupling capacitor (10- $\mu\text{F}$  tantalum recommended).
- R1 = Match value to line impedance
- FB** = Ferrite Bead
- $\text{\textcircled{G}}$  = Via To GND Plane



**Figure 5. Recommended Board Layout (2-Layer Board)**

## Ordering Information

| Ordering Code | Package Name | Package Type                  |
|---------------|--------------|-------------------------------|
| W183          | G            | 14-Pin Plastic SOIC (150-mil) |

Document #: 38-00798-A

